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I hereby revoke any previous Powers of Attorney and appoint **the practitioners at Customer Number 90828**, as its attorney or agent for so long as they remain with such firm, with full power of substitution and revocation, to prosecute the application, to make alterations and amendments therein, to transact all business in the U.S. Patent and Trademark Office in connection therewith, and to receive any Letters Patent, and for one year after issuance of such Letters Patent to file any request for a certificate of correction that may be deemed appropriate.

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APPENDIX A

MHKKG Ref.	Docket No.	App. No.	App. Date	Pat No	Pat Date	Title	Inventors
6363-11208	H1718 DIV2	12/330,459	12/8/2008			Shallow Trench Isolation Process And Structure With Minimized Strained Silicon Consumption	Xiang, Qi; Pan, James N.; Goo, Jung-Suk
6363-11700	H1775	10/790590	3/1/2004	7,543,256	6/2/2009	System And Method For Designing An Integrated Circuit Device	Lukanc, Tabery, Capodiec, Babcock, Kim, Spence, Haidinyak
6363-11800	F0996	09/816706	3/23/2001	6,996,124	2/7/2006	Mechanism To Strip LARQ Header And Regenerate FCS To Support Sleep Mode Wake Up	Chow
6363-11900	F0833	09/716215	11/21/2000	6,358,856	3/19/2002	Bright Field Image Reversal For Contact Hole Patterning	Christopher F. Lyons, Ramkumar Sumramanian, Marina V. Plat, Todd P. Lukanc
6363-12000	TT5956	11/259,572	10/26/2005	7576357	8/18/2009	System For Characterization Of Low-K Dielectric Material Damage	Jianhong Zhu, David Wu
6363-12100	G1160	09/994,358	11/26/2001	6,703,307	3/9/2004	Method Of Implantation After Copper Seed Deposition	Sergey D. Lopatin, Paul R. Besser, Matthew S. Buynoski
6363-12200	G0406	10/017,855	12/14/2001	6,828,259	12/7/2004	Enhanced Transistor Gate Using E-Beam Radiation	Philip A. Fisher; Chih-Yuh Yang; Marina V. Plat; Russell R.A. Callahan; Ashok M. Khathuria
6363-12300	F0799	10/083,914	2/27/2002	6,764,808	7/20/2004	Self-Aligned Pattern Formation Using Dual Wavelengths	Uzodinma Okoroanyanwe, Armando C. Botelli
6363-12400	H0137	10/190,138	7/3/2002			Method Of Using An Amorphous Carbon Layer For Improved Reticle Fabrication	Cyrus E. Tabery; Christopher F. Lyons

MHKKG Ref.	Docket No.	App. No.	App. Date	Pat No	Pat Date	Title	Inventors
6363-12500	G1162	09/994,395	11/26/2001			Method Of Using Ternary Copper Alloy To Obtain A Low Resistance And Large Grain Size Interconnect	Sergey D. Lopatin ; Paul R. Besser; Pin-Chin Connie Wang
6363-12600	G1154	10/016702	12/11/2001	6,675,369	1/6/2004	Method Of Enhancing Clear Field Phase Shift Masks By Adding Parallel Line To Phase 0 Region	Todd P. Lukanc, Christopher A. Spence
6363-12700	G1155	10/016273	12/11/2001	6,749,970	6/15/2004	Method Of Enhancing Clear Field Phase Shift Masks With Border Regions Around Phase 0 And Phase 180 Regions	Todd P. Lukanc, Christopher A. Spence
6363-12800	H0968P RV	60/415,178	9/30/2002			Strained Silicon Mosfet Having Improved Source/Drain Extension Dopant Diffusion Resistance And Method For Its Fabrication	Qi Xiang; Jung-Suk Goo, Haihong Wang
6363-12801	H0968	10/335,522	12/31/2002	6,756,276	6/29/2004	Strained Silicon Mosfet Having Improved Source/Drain Extension Dopant Diffusion Resistance And Method For Its Fabrication	Qi Xiang; Jung-Suk Goo, Haihong Wang
6363-12802	H0968DI V	10/872,707	6/21/2004	7,170,084	1/30/2007	Strained Silicon Mosfet Having Improved Source/Drain Extension Dopant Diffusion Resistance And Method For Its Fabrication	Qi Xiang; Jung-Suk Goo, Haihong Wang
6363-12803	H0968C NT	10/922,093	8/19/2004	7,268,066	9/11/2007	Strained Silicon Mosfet Having Improved Source/Drain Extension Dopant Diffusion Resistance And Method For Its Fabrication	Qi Xiang; Jung-Suk Goo, Haihong Wang